

STAC2942F

RF power transistors HF/VHF/UHF N-channel MOSFETs

Preliminary data

Features

- Gold metallization
- Excellent thermal stability
- Common source push-pull configuration
- POUT = 350 W min. with 21 dB gain @ 175
- In compliance with the 2002/95/EC European directive

Description

The STAC2942F is a gold metallized N-channel MOS field-effect RF power transistor. It is intended for use in 50 V DC large signal applications up to 250 MHz.

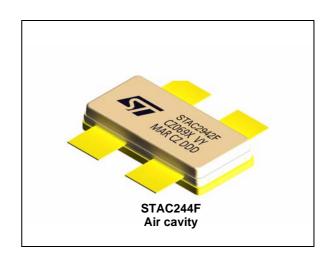


Figure 1. Pin connection

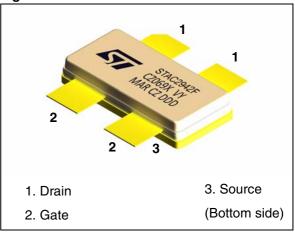


Table 1. Device summary

Order code	Marking	Package	Packaging
STAC2942F	STAC2942F	STAC244F	Plastic tray

Contents STAC2942F

Contents

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STAC2942F Electrical data

1 Electrical data

1.1 Maximum ratings

Table 2. Absolute maximum ratings ($T_{CASE} = 25 \,^{\circ}C$)

Symbol	Parameter	Value	Unit
V _{(BR)DSS} ⁽¹⁾	Drain source voltage	130	V
V _{DGR} ⁽¹⁾	Drain-gate voltage ($R_{GS} = 1 M\Omega$)	130	V
V _{GS}	Gate-source voltage	±20	V
I _D	Drain current	40	Α
P _{DISS}	Power dissipation	625	W
T _J	Max. operating junction temperature	200	°C
T _{STG}	Storage temperature	-65 to +150	°C

^{1.} T_J = 150 °C

1.2 Thermal data

Table 3. Thermal data

Symbol	Parameter	Value	Unit
R _{thJC}	Junction - case thermal resistance	0.28	°C/W

Electrical characteristics STAC2942F

2 Electrical characteristics

 $(T_{CASE} = 25 \, {}^{\circ}C)$

2.1 Static

Table 4. Static (per side)

Symbol	Test conditions				Тур.	Max.	Unit
V _{(BR)DSS} ⁽¹⁾	$V_{GS} = 0 V$	$I_{DS} = 100 \text{ mA}$		130			V
I _{DSS}	V _{GS} = 0 V	$V_{DS} = 50 \text{ V}$				100	μΑ
I _{GSS}	V _{GS} = 20 V	$V_{DS} = 0 V$				250	nA
V _{GS(Q)}	V _{DS} = 10 V	$I_D = 250 \text{ mA}$		1.5	2.5	4.0	V
V _{DS(ON)}	V _{GS} = 10 V	I _D = 10 A				3.0	٧
G _{FS}	V _{DS} = 10 V	I _D = 5 A		5			S
C _{ISS}					425		pF
C _{OSS}	$V_{GS} = 0 V$	$V_{DS} = 50 \text{ V}$	f = 1 MHz		202		pF
C _{RSS}					12		pF

^{1.} T_J = 150 °C

2.2 Dynamic

Table 5. Dynamic

Symbol	Test conditions	Min.	Тур.	Max.	Unit
P _{OUT}	$V_{DD} = 50 \text{ V}, I_{DQ} = 2 \text{ x } 250 \text{ mA}, P_{IN} = 4 \text{ W}, f = 175 \text{ MHz}$	350	450		W
h _D	V _{DD} = 50 V, I _{DQ} = 2 x 250 mA, P _{IN} = 4 W, f = 175 MHz	60	75		%

STAC2942F Impedance

3 Impedance

Figure 2. Current conventions

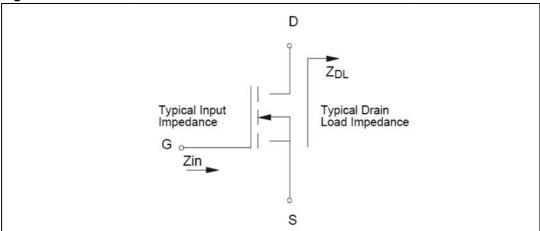


Table 6. Impedance data

Freq. (MHz)	Z _{IN} (Ω)	Z _{DL} (Ω)
175 MHz	2.0 - j2.0	3.5 + j5.2

Note: Measured gate to gate and drain to drain, respectively.

Typical performance STAC2942F

4 Typical performance

Figure 3. Capacitances vs drain supply Figure 4. Output power vs drain supply voltage

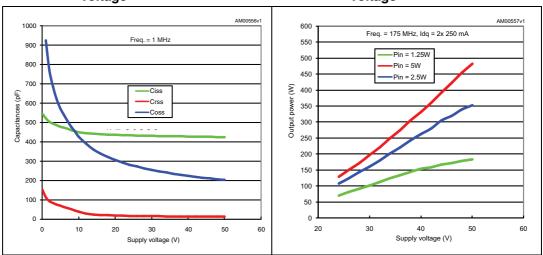
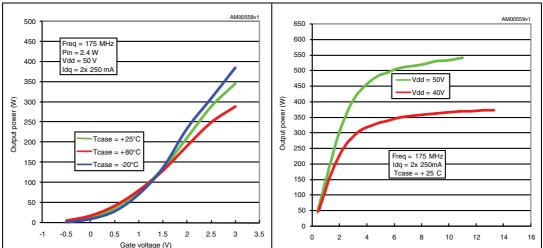


Figure 5. Output power vs gate voltage Figure 6. Output power vs input power



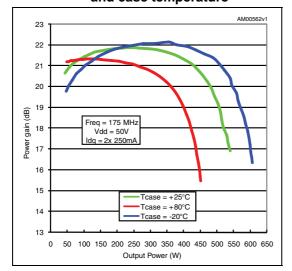
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STAC2942F Typical performance

Freq = 175 MHz Vdd = 50V Idq = 2x 250mA (M) 400 350 300 250 Efficiency (%) Freq = 175 MHz Vdd = 50V Idq = 2x 250mA Tcase = +25°C Tcase = +80°C Tcase = -20°C Tcase = +25°C Tcase = +80°C Tcase = -20°C 300 400 Output Power (W) Input Power (W)

Figure 7. Output power vs input power Figure 8. Efficiency vs output power and case temperature and case temperature

Figure 9. Power gain vs output power and case temperature



Test circuit STAC2942F

5 Test circuit

Figure 10. 175 MHz test circuit schematic (production test circuit)

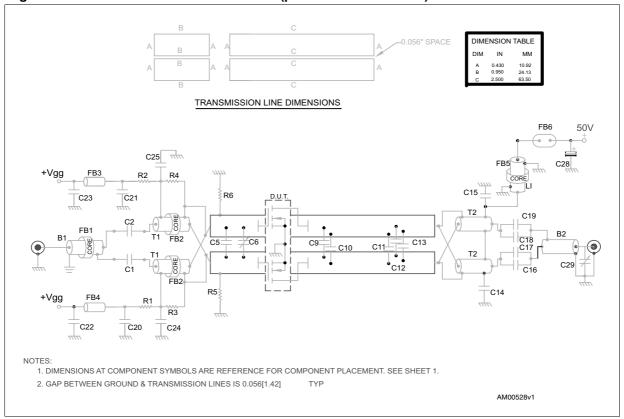


Table 7. 175 MHz test circuit component part list

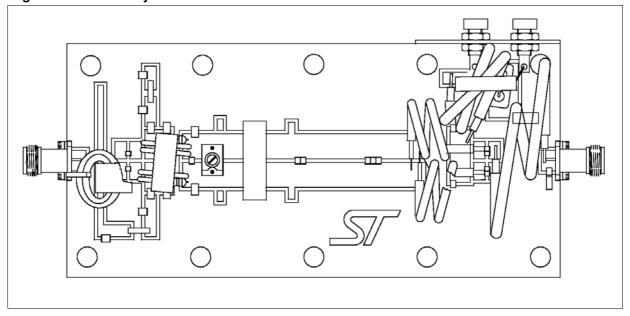
Component	Description
C1, C2, C14, C15, C24, C25	1200 pF ATC 700B chip capacitor
C5	75 pF ATC 100B chip capacitor
C6	ST406 variable capacitor
C9, C10	47 pF ATC 100B chip capacitor
C11, C12, C13	43 pF ATC 100B chip capacitor
C16, C18	470 pF ATC 100B chip capacitor
C17, C19, C20, C21	10,000 pF ATC 200B chip capacitor
C22, C23	.1 μF 200 V chip capacitor
C28	10 μF 100 V electrolytic capacitor
C29	.8 - 8 pF variable capacitor
R1, R2, R5, R6	430 Ω, 1/2 W chip resistor

STAC2942F Test circuit

Table 7. 175 MHz test circuit component part list (continued)

Component	Description
R3, R4	270 Ω 1/2 W axial lead resistor
B1	RG-316 50 Ω 11.8" thru ferrite toroid
B2	RG-142 50 Ω 11.8"
T1	4:1, RG-316 25 Ω, 5.9", 2 turns thru ferrite core
T2	1:4, 25 Ω semi-rigid cable, OD .141", 5.9"
L1	$\lambda/4$ inductor, RG-142 50 Ω , 11.8", 3 turns thru ferrite toroid
FB1,FB5	ferrite toroid
FB2, FB6	multi-aperture core
FB3, FB4	surface mount ferrite bead
PCB	Rogers ultralam 2000, Er 2.55, .060"

Figure 11. Circuit layout



6 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK® is an ST trademark.

Table 8. STAC244F package dimensions

Dim.	m	ım.	In	ch
Dilli.	Min	Max	Min	Max
А	5.10	5.59	200	220
A1	4.32	4.83	170	190
В	4.32	5.33	170	210
С	9.65	9.91	380	390
D	19.61	20.02	772	788
E	20.45	20.70	805	815
F	0.08	1.15	.003	.006
G	0.89	1.14	.035	.045
Н	1.45	1.70	.057	.067
I	3.18	4.32	.125	.170
J	9.27	9.53	.365	.375

10/13 Doc ID 17122 Rev 1

→ 2XA1 - - 4XA .07/1.8X45° 1 1 4X.020/0,51R. - 4X.005/0,13R. C 4X.030/0,76 R 3 3 4XB D Ε 4XF G SEATING PLANE 2 AM01112v1

Figure 12. Package dimensions

Revision history STAC2942F

7 Revision history

Table 9. Document revision history

Date	Revision	Changes
12-Feb-2010	1	First release

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